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Theoretical and numerical investigations on grain boundary migration due to inverse pinning

Munekazu Ohno ^a, Shinpei Ohyama ^b and Kiyotaka Matsuura ^a

^a *Division of Materials Science and Engineering, Faculty of Engineering, Hokkaido University, Kita 13 Nishi 8, Kita-ku, Sapporo, Hokkaido 060-8628, Japan*

^b *Graduate School of Engineering, Hokkaido University*

Corresponding author: Dr. Munekazu Ohno
Faculty of Engineering, Hokkaido University
Kita 13 Nishi 8, Kita-ku, Sapporo, 060-8628, Japan
Tel: +81-(0)11-706-6344
Fax: +81-(0)11-706-6344
E-mail address: mohno@eng.hokudai.ac.jp

Abstract :

Theoretical and numerical investigations are carried out into the inverse pinning effect of platelet particles on the grain boundary migration. The theoretical expression for the driving force of the inverse pinning proposed in an early work is first revisited and modified to remove the limitation in the volume fraction of the particles. In addition, it is shown that there exists the maximum velocity of the grain boundary due to the inverse pinning. The validity of the present considerations is demonstrated by phase-field simulations for the grain growth.

Keywords; Grain growth; Inverse pinning; Phase-field simulation

1. Introduction

Utilization of second phase particles in controlling grain structures of polycrystalline materials is one of the important techniques, the essential ingredient of which is the physics of the particle-boundaries interaction. It has been widely acknowledged that the existence of the particles causes retardation of the grain boundary migration during the grain growth processes. There have been a number of theoretical, experimental and simulation studies on this aspect, i.e., the pinning effect [1-10]. On the other hand, as exemplified by the case of AlN particles in steels [11], the particles with the anisotropic interfacial energy can induce and accelerate the migration of grain boundaries. Nishizawa called this phenomenon “inverse pinning” [11].

In contrast to the usual pinning effect, little has been clarified for the inverse pinning effect. It is often the case that interface properties between the matrix and second phase particle exhibit a strong anisotropy and, in this respect, the inverse pinning effect is considered as one of the effects often emerging in material production processes. This effect was recently investigated by phase-field simulations for the grain growth and it was found that it is highly possible that the inverse pinning causes the abnormal grain growth [12]. Hence, it is important to elucidate the detail of the inverse pinning effect, especially its kinetics.

Nishizawa proposed that the driving force for the inverse pinning of platelet particles ΔG_{inv} (J m^{-3}) can be approximated by the following equation [11].

$$\Delta G_{inv} = \frac{2v_m f_v}{w_p} (\sigma_2 - \sigma_1), \quad (1)$$

where v_m is the molar volume of the matrix, f_v is the volume fraction of the particle, w_p is the thickness of the platelet particles and $\sigma_1(\sigma_2)$ is the interfacial energy between the particle and grain 1 (grain 2). When $\sigma_2 > \sigma_1$, the boundary migrates due to ΔG_{inv} , yielding the growth of grain 1 and the shrink of grain 2. It should be pointed out that the detailed exposition was not given for the derivation of Eq. (1) in Ref. [11] and several important points remain to be analyzed and elucidated especially regarding the validity and application range of this equation. Although the validity of this relation was demonstrated for some cases by phase-field simulations [12], a more detailed and systematic investigation is required for deeper understanding of this effect and its practical utilization in material production processes. As will be shown later, Eq. (1) is validated for the system with small volume fraction of platelet particles. Therefore, it is not applicable to systems with relatively high volume fraction of the particles.

In this paper, Eq. (1) is first re-derived and modified to eliminate the limitation of the small volume fraction. Then, the kinetics of the inverse pinning is analyzed,

which elucidates the maximum velocity of the grain boundary moving due to the inverse pinning. Finally, the validity of these discussions is investigated by phase-field simulations.

2. Driving force of inverse pinning

The driving force of the inverse pinning ΔG_{inv} given by Eq. (1) is first reexamined. ΔG_{inv} is now expressed as $\Delta G_{\text{inv}} = v_m \Delta P_{\text{inv}}$ with the inverse pinning pressure ΔP_{inv} . For the sake of expedience, we shall consider the bi-crystalline material where the grains 1 and 2 are separately by the grain boundary normal to y direction and the platelet particles are regularly-arrayed periodically in x direction. The length (y -direction) and width (z -direction) of each platelet particle are assumed infinitely large compared with the thickness, w_p (x -direction). A part of this system is schematically shown in Fig. 1 (a) where L_x corresponds to a distance between the platelet particles periodically arraying in x -direction. The interfacial energy between the particle and the grain 1 (grain 2) is denoted by σ_1 (σ_2). When the grain boundary moves the distance of Δy in $+y$ direction, the resulting change of the total energy amounts to $2\Delta y L_z (\sigma_2 - \sigma_1)$. Hence, the energy change per the moved length, which corresponds to the inverse pinning force, is given by $2L_z (\sigma_2 - \sigma_1)$. The pressure exerting on the grain boundary, viz., the inverse pinning pressure is then obtained by dividing the inverse pinning force by the area of the grain boundary. When the particle thickness w_p is small compared with L_x , i.e., f_v is small, the area of the grain boundary can be approximated by $L_z L_x$. Then the pinning pressure is given by $\Delta P_{\text{inv}} = 2(\sigma_2 - \sigma_1)/L_x$. Since the volume fraction of the particle is $f_v = w_p/L_x$, one can obtain $\Delta P_{\text{inv}} = 2(f_v/w_p)(\sigma_2 - \sigma_1)$. The substitution of this relation into $\Delta G_{\text{inv}} = v_m \Delta P_{\text{inv}}$ yields Eq. (1).

As discussed above, Eq. (1) is considered applicable to the systems with the small volume fraction of particles, because the area of the grain boundary is approximated by $L_x L_z$ in its derivation. This limitation can be readily removed as follow. When w_p is not sufficiently small, the area of the grain boundary is not $L_x L_z$ but $(L_x - w_p)L_z$, as understood from Fig. 1(a). Hence, the inverse pinning pressure is given by $\Delta P_{\text{inv}} = 2L_z (\sigma_2 - \sigma_1) / ((L_x - w_p)L_z) = 2(\sigma_2 - \sigma_1) / (L_x - w_p)$. Using the relation $1/L_x = f_v/w_p$, the pinning pressure is rewritten as $\Delta P_{\text{inv}} = 2f_v (\sigma_2 - \sigma_1) / (w_p(1 - f_v))$. Hence, the driving force is given as

$$\Delta G_{\text{inv}} = v_m \Delta P_{\text{inv}} = \frac{2v_m}{w_p} \left(\frac{f_v}{1 - f_v} \right) (\sigma_2 - \sigma_1). \quad (2)$$

In contrast to Eq. (1), ΔG_{inv} in Eq. (2) is not proportional to f_v as is. This correction becomes important when f_v is high. It is noted that Eq. (2) is reduced to Eq. (1) when f_v

approaches null.

The most important fact understood from Eqs. (1) and (2) is that the driving force of the inverse pinning is proportional to the difference between the interfacial energies, i.e., $\Delta\sigma = \sigma_2 - \sigma_1$. However, the maximum value actually exists in the driving force, above which the driving force is independent of $\Delta\sigma$. In order to make this point clear, we re-derive Eq. (2) on the basis of the curvature of the grain boundary. It is generally accepted that the migration velocity of a segment of the grain boundary is proportional to the pressure difference caused by its local curvature [2]. This pressure is given by σ_g/r with the local curvature radius of the boundary r and the grain boundary energy σ_g . The inverse pinning pressure ΔP_{inv} can be derived from this relation by taking into account the change of the curvature radius due to the particle-boundary interaction. In the inverse pinning phenomenon, the grain boundary is generally curved near the triple junction because of the energy balance between σ_1 , σ_2 and σ_g . The two-dimensional image of the inverse pinning process is depicted in Fig. 1(b) where θ is the angle between y -axis and the grain boundary at the triple junction. If the shape of the whole grain boundary can be approximated by the segment of a single circle, its curvature radius r is described by $r = d/(2\cos\theta)$. Here, d is the thickness of the grain and it can be expressed in terms of f_v and w_p as $d = w_p(1-f_v)/f_v$. Hence, by substituting these relations into $\Delta P_{\text{inv}} = \sigma_g/r$, the following equation for ΔG_{inv} is obtained,

$$\Delta G_{\text{inv}} = \frac{2v_m\sigma_g}{w_p} \left(\frac{f_v}{1-f_v} \right) \cos\theta. \quad (3)$$

Here $\cos\theta$ is given as $\cos\theta = (\sigma_2 - \sigma_1)/\sigma_g$, provided that the shape of the boundary at the triple junction takes the equilibrium shape according to Young's law. Therefore, Eq. (3) is completely equivalent to Eq. (2). However, the form of Eq. (3) explicitly presents an important fact that the upper limit exists in ΔG_{inv} . The upper limit is realized when $\cos\theta = 1$. This condition corresponds to the complete wetting of the interface between the grain 1 and the particle by the grain 2.

Now, our focus is directed at the migration of the grain boundary due to the inverse pinning. The migration velocity of the grain boundary due to the inverse pinning V_g is given by using ΔP_{inv} as follows,

$$\begin{aligned} V_g &= m\Delta P_{\text{inv}} = m\sigma_g \frac{2}{w_p} \left(\frac{f_v}{1-f_v} \right) \cos\theta \\ &= 2\cos\theta V_{\text{ref}}, \quad (4) \end{aligned}$$

where m is the grain boundary mobility and

$$V_{\text{ref}} = m\sigma_g \frac{1}{w_p} \left(\frac{f_v}{1-f_v} \right) = \frac{m\sigma_g}{d}. \quad (5)$$

As already described above, d ($= w_p(1-f_v)/f_v$) is the thickness of the grain 2. V_{ref} is called the reference velocity in this paper and it can be regarded as the velocity of the boundary in the system without the effect of the particle as will be discussed in section 4. It is important to mention that the migration velocity of the grain boundary due to the inverse pinning is proportional to the reference velocity. The proportionality coefficient is entirely determined by the balance between the interfacial energies and the grain boundary energy. When the proportionality coefficient is maximum, viz., $\cos\theta = 1$, V_g becomes twice as large as the reference velocity, which is the upper limit of the velocity due to the inverse pinning.

It should be pointed out that Eq. (2) was derived without the detailed consideration of the shape of the grain boundary. On the other hand, Eq. (3) was derived in the light of the curvature of the grain boundary. But the curvature radius of the grain boundary was approximated by a single value of r . In this paper, the validity of Eqs. (2)-(4) is examined by the phase-field simulations.

3. Simulation method

In this study, we utilized the multi-phase-field model [13-15]. Within this model, the grain structure is characterized by a set of phase-fields, $\{\phi_i(\mathbf{r}, t)\}$. The phase-field $\phi_i(\mathbf{r}, t)$ corresponds to a probability of finding a grain having a crystallographic orientation specified by the subscript i ($i = 1, 2, 3, \dots, N$). Here, $\mathbf{r}$ is the spatial coordinate, t is the time and N is the total number of orientations considered in the simulation. ϕ_i varies from 0 to 1 and the grain boundary is described as the diffuse interface in which the orientation of grains gradually changes. The normalization condition $\sum_i^N \phi_i = 1$ is satisfied in each spatial point. When we define a step function s_i so that $s_i = 1$ when $\phi_i > 0$ and $s_i = 0$ otherwise, the number of phases coexisting in a given spatial point $S(\mathbf{r}, t)$ is given by $S(\mathbf{r}, t) = \sum_{i=1}^N s_i(\mathbf{r}, t)$. The time evolution of ϕ_i is described by the following equation [14],

$$\frac{\partial \phi_i}{\partial t} = \frac{2M_\phi}{S} \sum_{j \neq i}^N s_j s_i \left(\frac{\partial F}{\partial \phi_i} - \frac{\partial F}{\partial \phi_j} \right), \quad (6)$$

where M_ϕ is the phase-field mobility and

$$\frac{\partial F}{\partial \phi_i} = \sum_{k \neq i}^N \left(\frac{\epsilon_{ik}^2}{2} \nabla^2 \phi_k + \omega_{ik} \phi_k \right), \quad (7)$$

where ϵ_{ik} and ω_{ik} are the gradient energy coefficient and the height of the parabolic potential with a double obstacle in the ik interface. These parameters are related to the

interface thickness W and the interfacial energy σ_{ik} as given by $\epsilon_{ik} = 2\sqrt{W\sigma_{ik}}/\pi$ and $\omega_{ik} = 4\sigma_{ik}/W$ [14]. When the values of σ_{ik} and W are given, ϵ_{ik} and ω_{ik} are uniquely fixed. W was set to $6\Delta x$ with a square grid spacing Δx in all the simulations.

The time evolution equations (6) were discretized in a two-dimensional system based on standard second-order finite difference formulas with the square grid spacing Δx and these equations were solved using a simple first-order Euler scheme. Figure 2 represents the schematic illustration of the computational domain. There are the grain 1 at the bottom of the system and the grains 2 in the upper part of the grain 1. The second phase particles exist in the shape of platelet having a thickness of w_p . The computational domain corresponds to the rectangular area surrounded by the dashed line. The mirror boundary condition was applied to each edge in x -direction, while the no-flux boundary condition was set along each edge in y -direction. The initial curvature radius of the grain boundaries is equivalent to half of the system size of x -direction.

We have investigated the grain boundary migration in the system with the particle which is inert, viz., immobile. This process was simulated by solving the time evolution equations (6) for all the phase-fields except for the phase-field for the particle. In order to analyze the inverse pinning effect systematically, we focused on the processes with the different interfacial energies between the matrix and the particle. The interfacial energy between the grain 1 (grain 2) and particle is denoted by σ_1 (σ_2) and the grain boundary energy is described by σ_g . The difference $\Delta\sigma = \sigma_2 - \sigma_1$ was changed from 0 to 1.6 J m^{-2} and three values of $\sigma_g = 0.4, 0.79$ and 1.2 J m^{-2} were employed. The phase-field mobility was set to $M_\phi = 5.16 \times 10^{-3} \text{ m}^3 \text{ J}^{-1} \text{ s}^{-1}$. Although we do not specify the materials and the condition of the grain growth such as the temperature, a set of these input parameters reproduces the kinetics which is similar to the austenite grain growth of low carbon steels ($\sim 0.2 \text{ mass\%}$ carbon steel) at a relatively high temperature ($\sim 1740 \text{ K}$) [15]. In addition, the volume fraction and the particle thickness were chosen to be $f_v = 0 - 0.72$, $w_p = 0 - 36 \text{ }\mu\text{m}$. The square grid spacing Δx was set to $1.0 \text{ }\mu\text{m}$, unless otherwise stated. The time step Δt was given by $\Delta t = \Delta x^2 / (5M_\phi \epsilon_a^2)$ where ϵ_a is the maximum value among the different ϵ_{ik} associated with the different interfacial (grain boundary) energies. The simulations were conducted until the system reaches the steady state. The system size in x -direction was changed according to the given values of d and w_p , while the system size in y -direction was changed from $100 \text{ }\mu\text{m}$ to $500 \text{ }\mu\text{m}$ in order for the system to reach the steady state in all the growth conditions within reasonable computational times.

4. Results and discussion

We first investigate the grain boundary migration in the system without the second phase particle, from which the velocity equivalent to V_{ref} in Eq. (5) is calculated. Figure 3 represents the time evolution of the microstructure calculated for $d = 100 \mu\text{m}$ and $\sigma_g = 0.79 \text{ J m}^{-2}$. The grain boundary between the grains 1 and 2 moves upward with time. The temporal changes of the moved distance of the rearmost segment of the grain boundary are shown in Fig. 4(a) for different values of d . In all the cases, the velocity takes almost a constant after $t = 0.15 \text{ s}$. Figure 4(b) shows the moving velocity during the steady state (circle plots) obtained for the different values of d .

The Allen-Cahn type Eq. (6) exactly reproduces the well-known relationship for the curvature-driven motion of the boundary as given by $v = -m\sigma_g/r$ where v is the normal velocity of the grain boundary. Furthermore, the present phase-field model exactly reproduces von Neumann-Mullins law of two-dimensional grain growth kinetics [14]. This indicates that the kinetics of triple junctions does not directly affect the grain growth and the contact angles at the triple junction always comply with the equilibrium relationship, i.e., Young's law. The angle θ_i shown in Fig. 3(b) indicate the angle between y -axis and the grain boundary at the triple junction. Using θ_i , r is given by $r = d/(2\cos\theta_i)$ with the grain thickness d . In Figs. 3(b) and (c), the contact angle of the grain boundaries at the triple junction is 120° and θ_i is accordingly 60° in all the cases. Hence, the moving velocity of the boundary v is given by $v = m\sigma_g/d$. This is equivalent to the velocity V_{ref} defined in Eq. (5). The calculated result of Eq. (5) is indicated by the solid line in Fig. 4(b). The results of phase-field simulation are completely in accord with Eq. (5).

The inverse pinning effect is discussed. Figure 5 shows the snapshots of the microstructure during the processes with the platelet particle, obtained from the phase-field simulations for $d = 88 \mu\text{m}$, $w_p = 12 \mu\text{m}$, $\sigma_g = \sigma_1 = 0.79 \text{ J m}^{-2}$ and the different values of σ_2 and thus different values of $\Delta\sigma (= \sigma_2 - \sigma_1)$. In the case of $\Delta\sigma = 0$ (Fig. 5(a)), the grain boundary is completely pinned by the platelet particle. Namely the usual pinning effect is observed for $\Delta\sigma = 0$. The complete stop of the grain boundary can be understood from the fact that the shape of the grain boundary is straight, viz., the curvature is null. When $\Delta\sigma$ increases (Figs. 5(b) and (c)), the grain boundary is curved. In these cases, the grain boundary moves with the time. When $\Delta\sigma = 1.6 \text{ J m}^{-2}$ (Fig. 5(d)), the grain boundary does not directly touch the particle, being more curved. In this case, the interface between the particle and grain 2 is completely wetted by the grain 1. It moves with higher velocity than those in the former cases of $\Delta\sigma = 0.16$ and 0.47 J m^{-2} . The dependences of the moving velocity V_g on $\Delta\sigma$ were calculated for different sets of σ_g , σ_1 and σ_2 . The results are shown in Fig. 6. In each set of data, the values of σ_g and

σ_1 are fixed and σ_2 is varied. In all the cases, V_g increases with increase in $\Delta\sigma$. When the particle does not exist, the moving velocity V_{ref} for $d = 88 \mu\text{m}$ corresponds to about $220 \mu\text{m s}^{-1}$ as shown in Fig. 4(b). Hence, the grain boundary migration is accelerated by the particle in all the cases when $\Delta\sigma$ is sufficiently high.

It is noted in Fig. 6 that V_g shows the upper limit for each value of σ_g when $\Delta\sigma$ takes high values. For instance, when $\sigma_g = \sigma_1 = 0.79 \text{ J m}^{-2}$, V_g takes almost a constant value of about $700 \mu\text{m s}^{-1}$ for $\Delta\sigma > 0.8 \text{ J m}^{-2}$. According to Eq. (4), this upper limit is given by $2V_{\text{ref}}$. In order to see the validity of Eq. (4), V_g is divided by V_{ref} calculated for $d = 88 \mu\text{m}$ and its normalized velocity is plotted against $\Delta\sigma/\sigma_g (= \cos\theta)$ in Fig. 7 where the solid line indicate the relation $V_g/V_{\text{ref}} = 2\cos\theta$, viz., Eq. (4). Regardless of the values of σ_g and σ_1 , all data merge into the single curve of $V_g/V_{\text{ref}} = 2\cos\theta$. When $\Delta\sigma/\sigma_g$ is less than 0.5, this theoretical relation is in complete agreement with the results of the phase-field simulations. On the other hand, for $\Delta\sigma/\sigma_g > 0.5$, the results of the simulations deviate from this theoretical relation. However, this does not indicate the failure of Eq. (4). This is due to the numerical error in the phase-field simulations. When $\Delta\sigma/\sigma_g > 0.5$, the contact angle of the boundaries at the triple junction θ becomes very small. We found it quite difficult to precisely describe such small angles in the present phase-field simulations. This error can be gradually reduced by decreasing Δx . The dependence of the results of phase-field simulation on Δx is shown in Fig. 8. The data of the phase-field simulations gradually approach the solid line of Eq. (4) as Δx decreases. Hence, the present simulations show the validity of Eq. (4) regarding the dependence of V_g on $\Delta\sigma/\sigma_g$. It is noted that the convergence is not fast in Fig. 8 and therefore we decided to use $\Delta x = 1.0 \mu\text{m}$ in the light of the computational burden and the accuracy.

Figure 9 represents the dependence of V_g on $\Delta\sigma/\sigma_g$ calculated for $w_p = 12 \mu\text{m}$, $\sigma_g = \sigma_1 = 0.79 \text{ J m}^{-2}$ and the different value of f_v . The solid lines are the results of Eq. (4) for the different value of f_v . Although there are the differences between Eq. (4) and the simulation results for high values of $\Delta\sigma/\sigma_g$ due to the numerical error described above, the results of Eq. (4) coincide well with those of phase-field simulations for each value of f_v .

As described in section 2, the essential difference between Eqs. (1) and (2) is in the dependence of ΔG_{inv} (thus V_g) on f_v and w_p . According to Eq. (1), V_g is determined only by the ratio of f_v/w_p for a given value of $\Delta\sigma$. In other words, it should be independent of w_p or f_v as long as the ratio f_v/w_p is a constant. The dependences of V_g on w_p for fixed values of w_p/f_v are shown in Fig. 10 where the plots and the solid lines are the results of the phase-field simulations and Eq. (4), respectively. $\Delta\sigma$ was set to $\Delta\sigma =$

0.5. V_g clearly depends on w_p even though f_v/w_p is fixed, which indicate that Eq.(1) is not applicable to the system with high volume fraction. On the other hand, the simulation results agree well with the results of Eq. (4) and it shows the validity of Eqs. (2) and (3). The correction as given by Eqs. (2) and (3) becomes important when f_v exceeds 0.1.

As demonstrated above, the present phase-field simulations demonstrated the validity of Eqs. (2)-(4). It is important to use Eq. (2) or (3) instead of Eq. (1) when the volume fraction of particles is relatively high. In addition, there exists the maximum velocity of grain boundary migrating due to the inverse pinning force, which is determined not by $\Delta\sigma = \sigma_2 - \sigma_1$ but by m and σ_g for given volume fraction and thickness of the particles.

5. Summary

In this study, the theoretical and numerical investigations were carried out into effects of the inverse pinning of platelet particles on the grain boundary migration. The theoretical expression for the driving force of the inverse pinning of platelet particles proposed in the early report [11] was first derived and it was discussed that this expression is valid for the system with small volume fraction. In this paper, we derived the driving force of the inverse pinning which is free from the limitation in the volume fraction. In addition, by considering the curvature-driven motion of the boundary, we showed that the velocity of the grain boundary reaches at its maximum in the complete wetting condition. These theoretical considerations were then examined by the phase-field simulations for the grain growth. The validity of our discussions was successfully demonstrated.

The focus in this paper was placed on the very simplified system where the platelet particles having infinitely large length and width are regularly arrayed along x -direction. In reality, however, the precipitates have finite length and width and they are not regularly arrayed. The development for the theory of inverse pinning for more general cases remains to be tackled in a future work.

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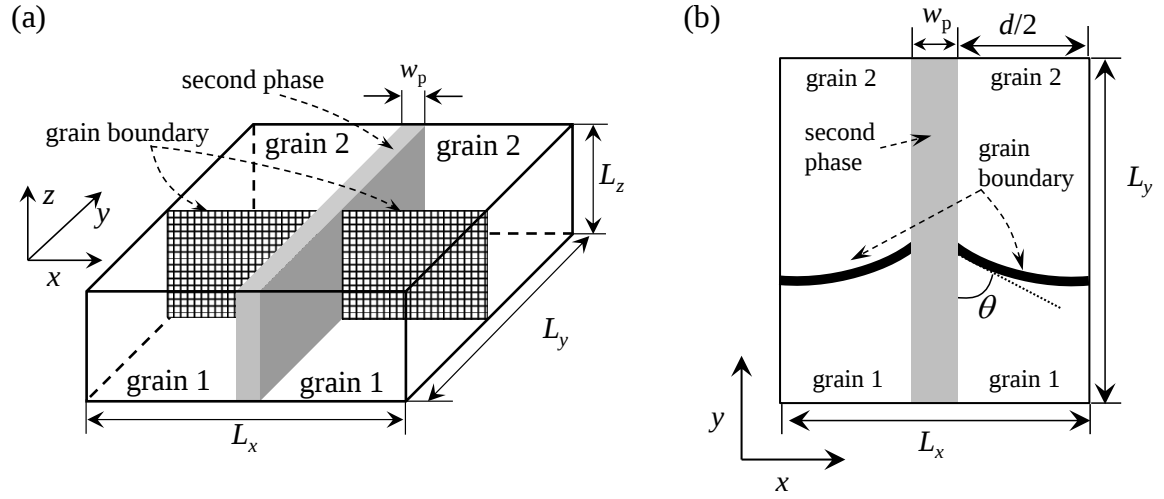


Fig. 1. (a) three-dimensional and (b) two-dimensional illustrations of the inverse pinning process.

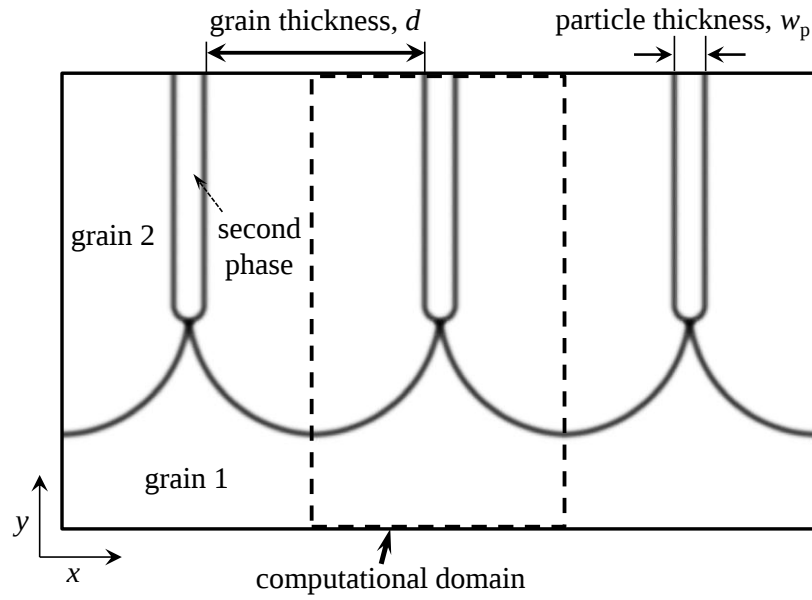


Fig. 2. Schematic illustration of computational domain (surrounded by dashed line).

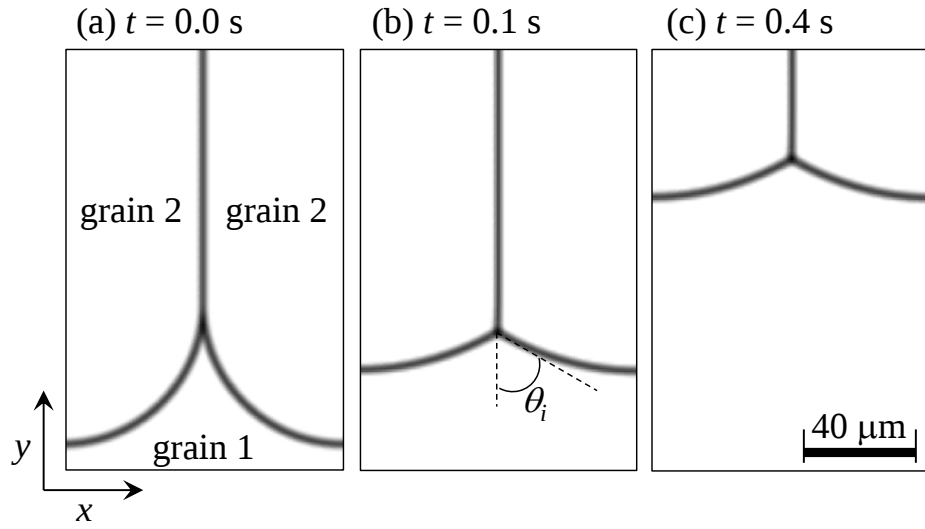
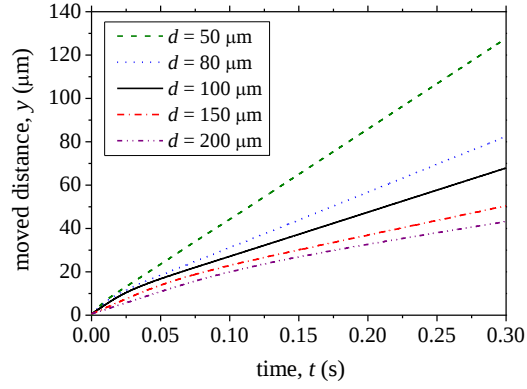


Fig. 3. Snapshots of microstructures during the grain growth without the second phase particles at different times. Thick lines indicate the grain boundaries in each figure.

(a)



(b)

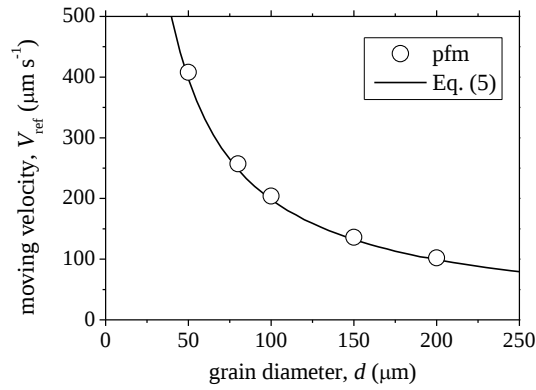


Fig. 4. (a) Time change of moved distance for different value of d in the system without the second phase. (b) Dependence of moving velocity during the steady state V_{ref} on d . The plots are the results of phase-field simulations, while the solid line indicates the result of Eq. (5).

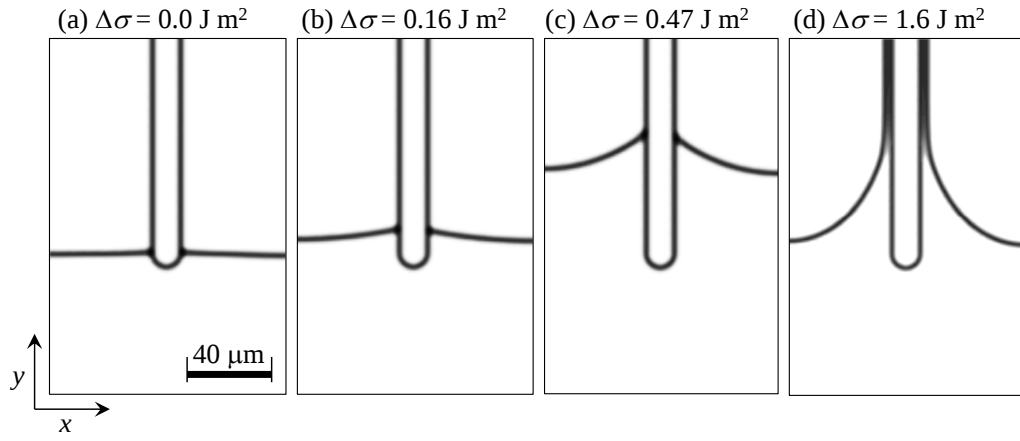


Fig. 5. Snapshots of microstructure with the second phase particle at (a)–(c) $t = 0.3$ and (d) $t = 0.15 \text{ s}$ simulated for $d = 88 \text{ } \mu\text{m}$, $w_p = 12 \text{ } \mu\text{m}$, $\sigma_g = \sigma_1 = 0.79 \text{ J m}^{-2}$ and the different values of $\Delta\sigma = \sigma_2 - \sigma_1$.

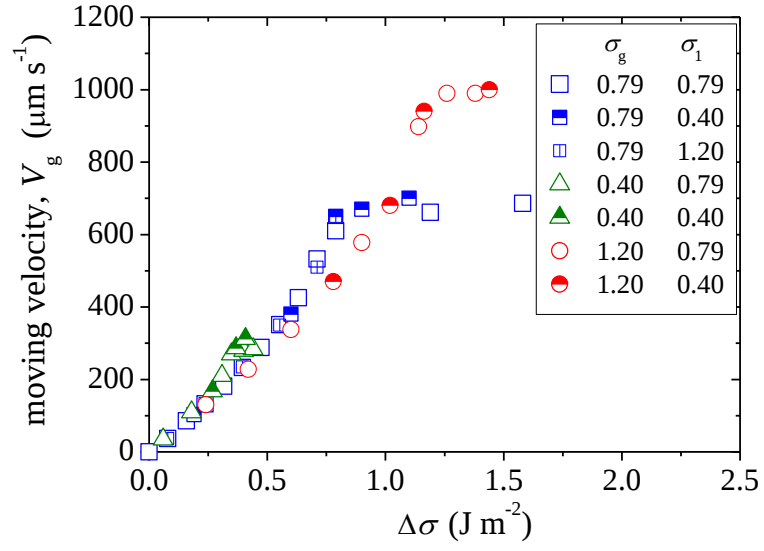


Fig. 6. Dependences of V_g on $\Delta\sigma$ calculated for $d = 88 \mu\text{m}$, $w_p = 12 \mu\text{m}$ and different sets of σ_g , σ_1 and σ_2 . In the legend, the values of interfacial energies are denoted in the unit of J m^{-2} .

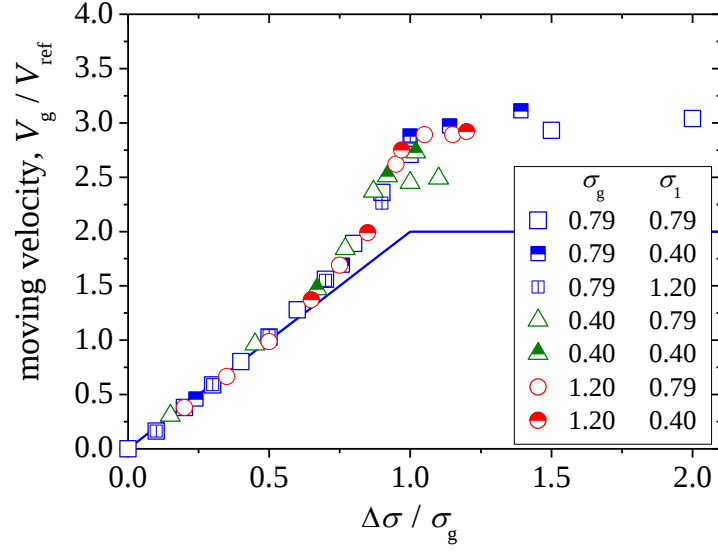


Fig. 7. Dependences of V_g / V_{ref} on $\Delta\sigma / \sigma_g$ calculated for $\Delta x = 1 \mu\text{m}$, $d = 88 \mu\text{m}$, $w_p = 12 \mu\text{m}$ and different sets of σ_g , σ_1 and σ_2 . In the legend, the values of interfacial energies are denoted in the unit of J m^{-2} . The solid line indicates the result of Eq. (4).

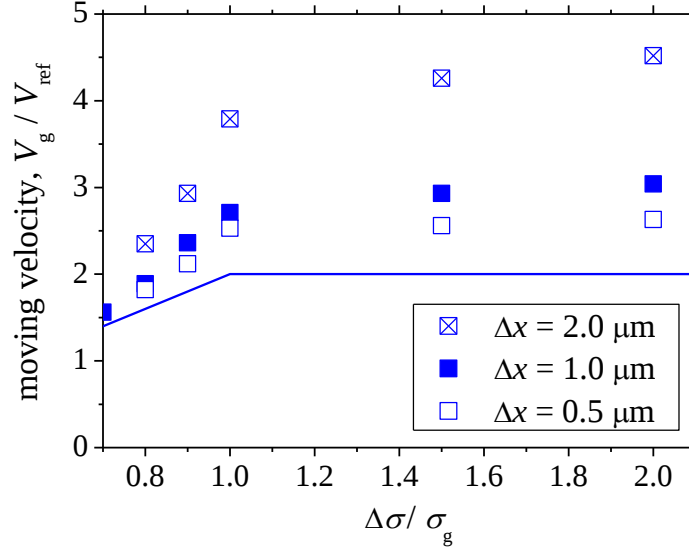


Fig. 8. Grid size dependence of V_g / V_{ref} calculated for $\sigma_g = \sigma_1 = 0.79 \text{ J m}^{-2}$. The solid line indicates the result of Eq. (4).

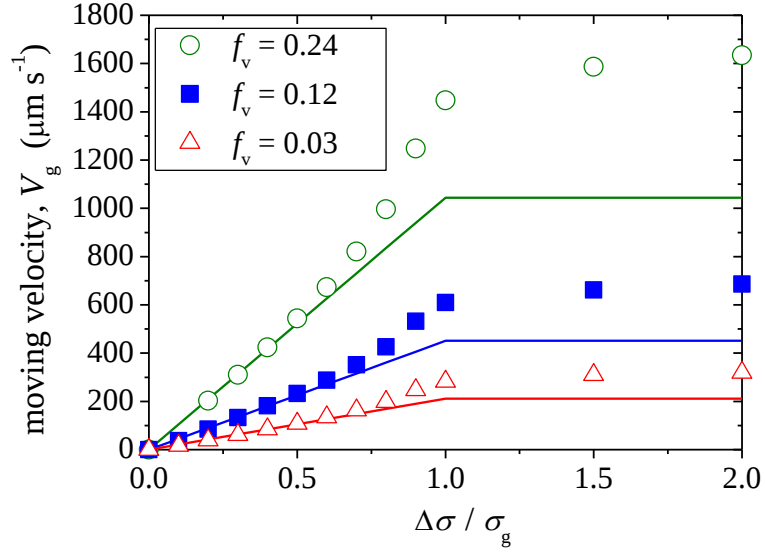


Fig. 9. V_g with respect to $\Delta\sigma/\sigma_g$ calculated for $w_p = 12 \mu\text{m}$, $\sigma_g = \sigma_1 = 0.79 \text{ J m}^{-2}$ and the different values of f_v . Three lines are the results of Eq. (4) for three values of f_v .

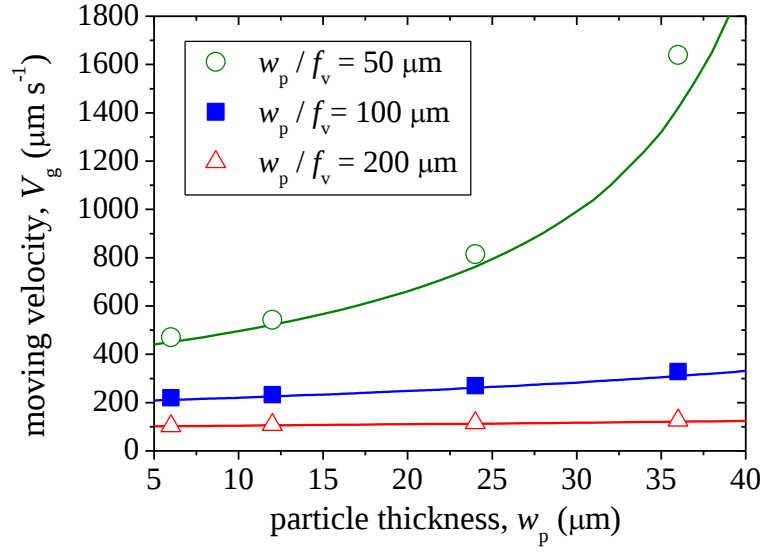


Fig. 10. Dependence of V_g on w_p calculated for $\Delta\sigma/\sigma_g = 0.5$ and the different values of w_p/f_v . The lines are the results of Eq. (4) for three values of w_p/f_v .